SONY

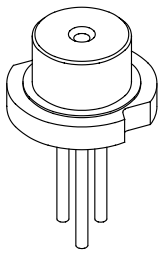
SLD1135VS

650nm Index-Guided Red Laser Diode

Description

The SLD1135VS is a index-guided red laser diode for Laser pointer. The wavelength is 20nm shorter than SLD1122VS.

M-294



Features

- Small astigmatism (7µm typ.)
- Small package (ϕ5.6mm)
- Single longitudinal mode
- Low operating voltage (2.5V Max)
- Max operating temperature = 40°C (Case temperature)

Applications

Laser pointer

Structure

- AlGaInP MQW laser diode
- PIN photodiode to monitor laser beam output

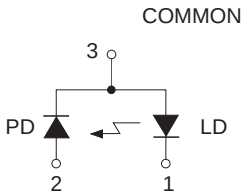
Recommend Optical Power Output

5mW

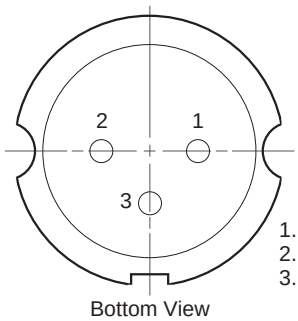
Absolute Maximum Ratings (Tc = 25°C)

• Optical power output	Po		5	mW
• Reverse voltage	V_R	LD	2	V
		PD	15	V
• Operating temperature	Topr		–10 to +40	°C
• Storage temperature	Tstg		–40 to +85	°C

Connection Diagram



Pin Configuration



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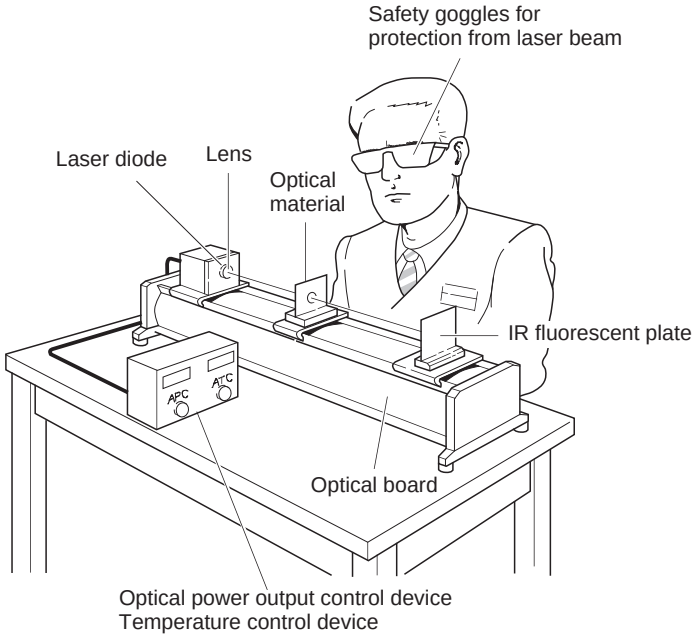
Electrical and Optical Characteristics (Tc = 25°C) Tc: Case temperature

Item		Symbol	Conditions	Min.	Typ.	Max.	Unit
Threshold current		Ith			30	40	mA
Operating current		Iop	Po = 5mW		35	45	mA
Operating voltage		Vop	Po = 5mW		2.2	2.5	V
Wavelength		λp	Po = 5mW		650	660	nm
Radiation angle	Perpendicular	θ⊥	Po = 5mW	22	30	40	degree
	Parallel	θ//		5	7	12	degree
Positional accuracy	Position	ΔX, ΔY, ΔZ	Po = 5mW			±150	µm
	Angle	Δϕ//				±3	degree
		Δϕ⊥				±3	degree
Differential efficiency		ηD	Po = 5mW	0.3	0.6	0.9	mW/mA
Astigmatism		As	Po = 5mW		7	15	µm
Monitor current		Imon	Po = 5mW, V_R = 5V	0.05	0.1	0.25	mA

Handling Precautions

(1) Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 4W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm^2. Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

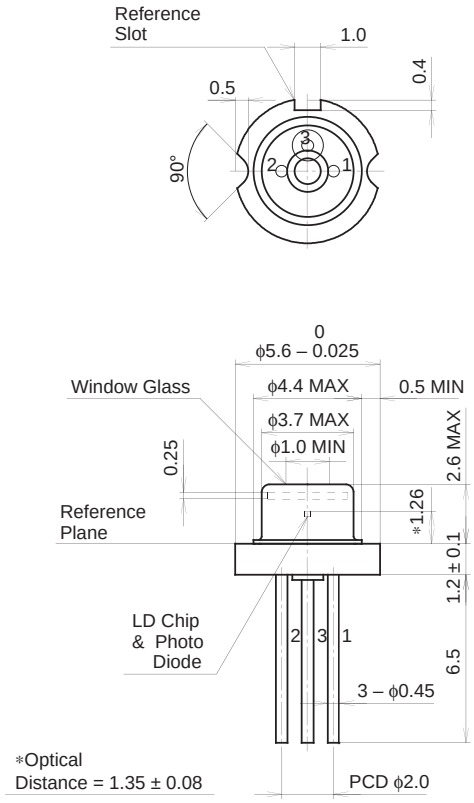


(2) Prevention of surge current and electrostatic discharge

Laser diode is most sensitive to electrostatic discharge among semiconductors. When a large current is passed through the laser diode even for an extremely short time (in the order of nanosecond), the strong light emitted from the laser diode promotes deterioration and then laser diodes are destroyed. Therefore, note that the surge current should not flow the laser diode driving circuit from switches and others. Also, if the laser diode is handled carelessly, it may be destructed instantly because electrostatic discharge is easily applied by a human body. Be great careful about excess current and electrostatic discharge.

Package Outline Unit: mm

M-294



SONY CODE	M-294
EIAJ CODE	————
JEDEC CODE	————

PACKAGE WEIGHT	0.3g